Characteristics STPS41H100C-Y

1 Characteristics

Table 2. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage, T _j = -40 °C			100	V
I _{F(RMS)}	Forward rms current			30	Α
	Average forward current, δ = 0.5, T_c = 150 °C		Per diode	20	Α
I _{F(AV)}	Average forward current, 0 = 0.5, 1 _c = 150°C	Per device	40	^	
I _{FSM}	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		220	Α	
P _{ARM} ⁽¹⁾	Repetitive peak avalanche power $t_p = 10 \mu s$, $T_j = 125 °C$		1300	W	
T _{stg}	Storage temperature range			-65 to +175	°C
Tj	Operating junction temperature ⁽²⁾			-40 to +175	°C

^{1.} For pulse time duration derating, please refer to *Figure 3*. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the STMicroelectronics Application notes AN1768, "Admissible avalanche power of Schottky diodes" and AN2025, "Converter improvement using Schottky rectifier avalanche specification".

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit
D	Junction to case	1.5	
R _{th(j-c)}	Per device	0.8	°C/W
R _{th(c)}	Coupling	0.1	

When the diodes 1 and 2 are used simultaneously: $\Delta Tj(diode 1) = P(diode1) \times R_{th(i-c)}(Per diode) + P(diode 2) \times R_{th(c)}(Per diode) + P(diode 3) \times R_{th(c)}(Per diode)$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	$V_R = V_{RRM}$	-	-	10	μΑ
		T _j = 125 °C		-	3	10	mA
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 20 A	-	-	0.80	V
		T _j = 125 °C		-	0.62	0.67	
		T _j = 25 °C	I _F = 40 A	-	-	0.90	
		T _j = 125 °C		-	0.70	0.76	

^{1.} Pulse test: $t_p = 5 \text{ ms}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.58 \times I_{F(AV)} + 0.0045 \times I_{F^{2}(RMS)}$$

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^{2.} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

^{2.} Pulse test: $t_p = 380 \mu s$, $\delta < 2\%$

STPS41H100C-Y Characteristics

Figure 1. Average forward power dissipation versus average forward current (per diode)

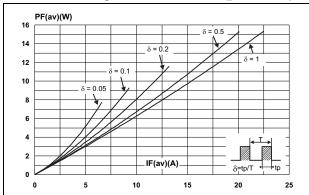


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

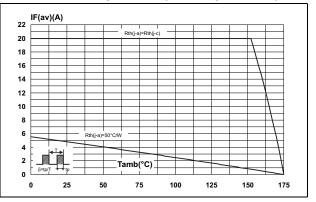
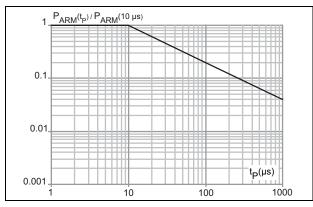


Figure 3. Normalized avalanche power derating versus pulse duration

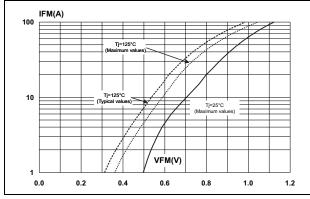
Figure 4. Relative variation of thermal impedance junction to case versus pulse duration (per diode)

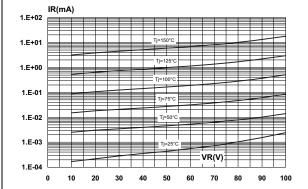


Zth(j-c)/Rth(j-c) 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 tp(s) 0.0 1.E-03 1.E-01 1.E+00

Figure 5. Forward voltage drop vs. forward current (per diode)

Figure 6. Reverse leakage current versus reverse voltage applied (typical values, per diode)

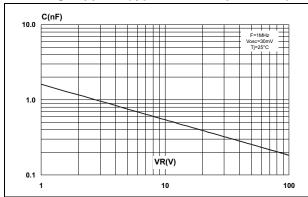


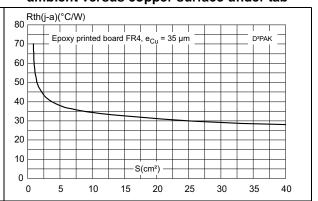


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Figure 7. Junction capacitance vs. reverse voltage applied (typical values, per diode)

Figure 8. Thermal resistance junction to ambient versus copper surface under tab





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STPS41H100C-Y Package information

2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Cooling method: by conduction (C)
- Recommended torque value for TO-220AB: 0.55 N·m
- Maximum torque value for TO-220AB: 0.7 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 9. D²PAK dimension definitions Α C2 L2 D L3 R B2 В G V2 * Flat zone no less than 2 mm



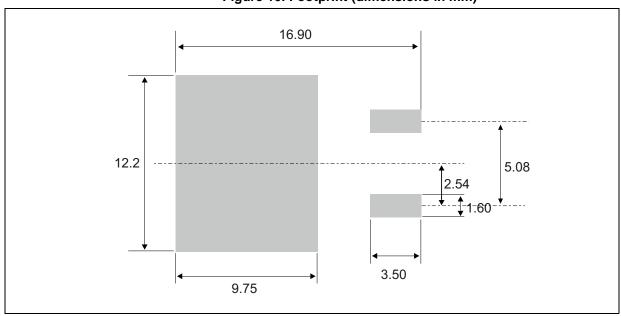
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Package information STPS41H100C-Y

Table 5. D²PAK dimension values

	Dimensions					
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	4.40		4.60	0.173		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
В	0.70		0.93	0.027		0.037
B2	1.14		1.70	0.045		0.067
С	0.45		0.60	0.017		0.024
C2	1.23		1.36	0.048		0.054
D	8.95		9.35	0.352		0.368
E	10.00		10.40	0.393		0.409
G	4.88		5.28	0.192		0.208
L	15.00		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.30		1.75	0.051		0.069
М	2.29		2.79	0.090		0.110
R		0.40 typ.			0.016 typ.	
V2	0°		8°	0°		8°

Figure 10. Footprint (dimensions in mm)



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STPS41H100C-Y Package information

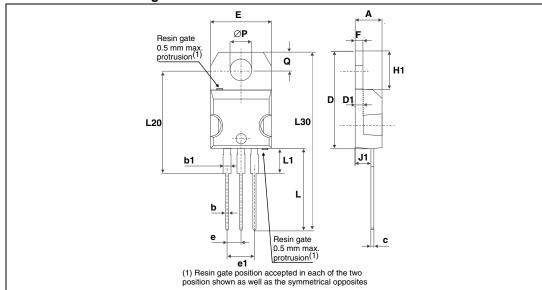


Figure 11. TO-220AB dimension definitions

Table 6. TO-220AB dimensions

	Dimensions				
Ref.	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	4.40	4.60	0.17	0.18	
b	0.61	0.88	0.024	0.035	
b1	1.14	1.70	0.045	0.067	
С	0.48	0.70	0.019	0.027	
D	15.25	15.75	0.60	0.62	
D1	1.27 typ.		0.05 typ.		
E	10	10.40	0.39	0.41	
е	2.40	2.70	0.094	0.106	
e1	4.95	5.15	0.19	0.20	
F	1.23	1.32	0.048	0.052	
H1	6.20	6.60	0.24	0.26	
J1	2.40	2.72	0.094	0.107	
L	13	14	0.51	0.55	
L1	3.50	3.93	0.137	0.154	
L20	16.40 typ.		0.64 typ.		
L30	28.90 typ.		1.13 typ.		
ØP	3.75	3.85	0.147	0.151	
Q	2.65	2.95	0.104	0.116	



Ordering information STPS41H100C-Y

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS41H100CGY-TR	STPS41H100CGY	D²PAK	1.48 g	1000	Tape and reel
STPS41H100CTY	STPS41H100CY	TO-220AB	2.20 g	50	Tube

4 Revision history

Table 8. Revision history

Date	Revision	Changes
21-Oct-2011	1	Initial release.
14-Jan-2015	2	Added TO-220AB package information. Updated <i>Table 2</i> and <i>Figure 3</i> . Removed <i>Figure 4</i> .

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